Application No.: 10/722,576 2 Docket No.: 543822002600

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims

1. (Currently amended) A process for controlling a PMC memory component, comprising: sending out a signal to select one of several possible modes for the PMC memory component; and

operating the PMC memory component in accordance with the specific mode selected by the signal, wherein depending on the specific mode selected the PMC memory component is brought into states of different storage permanence by correspondingly selecting a current intensity and/or a duration of a programming pulse, and/or a number of programming pulses.

- 2. (Previously presented) The process of claim 1, further comprising writing data into the memory component in accordance with the specific mode selected by the signal.
- 3. (Previously presented) The process of claim 2, whereby one of the modes is a soft writing mode.
- 4. (Previously presented) The process of claim 2, whereby one of the modes is a non-volatile writing mode.
- 5. (Previously presented) The process of claim 2, whereby one of the modes is a hard writing mode.
- 6. (Previously presented) The process of claim 2, whereby for the writing of data into the memory component, a current intensity, a duration of a programming pulse is adapted, and/or a number of programming pulses.
- 7. (Original) The process of claim 1, whereby the memory component comprises PMC

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memory cells.

8. (Original) The process of claim 1, whereby the signal is sent out over one or several separate mode selection lines.

- 9. (Original) The process of claim 1, whereby the signal is sent out over the same line as actual data to be stored in the memory component.
- 10. (Previously presented) The process of claim 9, whereby the signal is sent out over the line by use of memory mode selection bits, the bits being followed by bits carrying the data to be stored in the memory component.
- 11. (Currently amended) A memory system, comprising:
 - a memory component; and
- a controller adapted to operate the memory component in at least one of several different modes by bringing the memory component into states of different storage permanence by correspondingly selected a current intensity of a programming pulse.
- 12. (Previously presented) The system of claim 11, whereby one of the modes is a soft writing mode.
- 13. (Previously presented) The system of claim 11, whereby one of the modes is a non-volatile writing mode.
- 14. (Previously presented) The system of claim 11, whereby one of the modes is a hard writing mode.
- 15. (Original) The system of claim 11, whereby the memory component comprises PMC memory cells.

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- 16. (New) A process for controlling a PMC memory component, comprising:

 sending out a signal to select one of several modes for the PMC memory component; and operating the PMC memory component in accordance with the mode selected by the signal, wherein depending on the mode selected the PMC memory component is brought into states of different storage permanence by correspondingly selecting a duration of a programming pulse.
- 17. (New) A process for controlling a PMC memory component, comprising:
 sending out a signal to select one of several modes for the PMC memory component; and
 operating the PMC memory component in accordance with the mode selected by the signal,
 wherein depending on the mode selected the PMC memory component is brought into states of
 different storage permanence by correspondingly selecting a number of programming pulses.
- 18. (New) A memory system, comprising:

a memory component; and

a controller adapted to operate the memory component in several different modes by bringing the memory component into states of different storage permanence by correspondingly selecting a duration of a programming pulse.

19. (New) A memory system, comprising:

a memory component; and

a controller adapted to operate the memory component in several different modes by bringing the memory component into states of different storage permanence by correspondingly selecting a number of programming pulses.